

IXFP4N60P3

Request a Quote

IXFP4N60P3 Information

Part Number	IXFP4N60P3
Manufacturer	IXYS
Category	Discrete Semiconductor Products Transistors - FETs, MOSFETs - Single
Description	MOSFET N-CH 600V 4A TO-220AB
Package	TO-220-3
	For the pricing/inventory/lead time, please contact us Website: https://www.heisener.com E-mail: salesdept@heisener.com
	Manufacturer Category Description

Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.



IXFP4N60P3 Specifications

Manufacturer Part Number	IXFP4N60P3
Manufacturer	IXYS
Category	Discrete Semiconductor Products
	Transistors - FETs, MOSFETs - Single
Package	TO-220-3
Series	HiPerFET?, Polar3?
FET Type	N-Channel
Technology	MOSFET (Metal Oxide)
Drain to Source Voltage (Vdss)	600V
Current - Continuous Drain (Id) @ 25°C	4A (Tc)
Drive Voltage (Max Rds On, Min Rds On)	10V
Vgs(th) (Max) @ Id	5V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	6.9nC @ 10V
Input Capacitance (Ciss) (Max) @ Vds	365pF @ 25V
Vgs (Max)	$\pm 30 V$
FET Feature	-
Power Dissipation (Max)	114W (Tc)
Rds On (Max) @ Id, Vgs	2.2 Ohm @ 2A, 10V
Operating Temperature	-55°C ~ 150°C (TJ)
Mounting Type	Through Hole
Supplier Device Package	TO-220AB
Package / Case	TO-220-3
	Report errors?

IXFP4N60P3 Guarantees



Quality Guarantees

We provide 90 days warranty. * If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.

SERVICE BUARANTEE

Service Guarantees

We guarantee 100% customer satisfaction. Our experienced sales team and tech support team back our services to satisfy all our customers.

IXFP4N60P3 Payment Methods



IXFP4N60P3 Shipping Methods



If you have any question about IXFP4N60P3, please do not hesitate to contact us! Website: https://www.heisener.com E-mail: salesdept@heisener.com